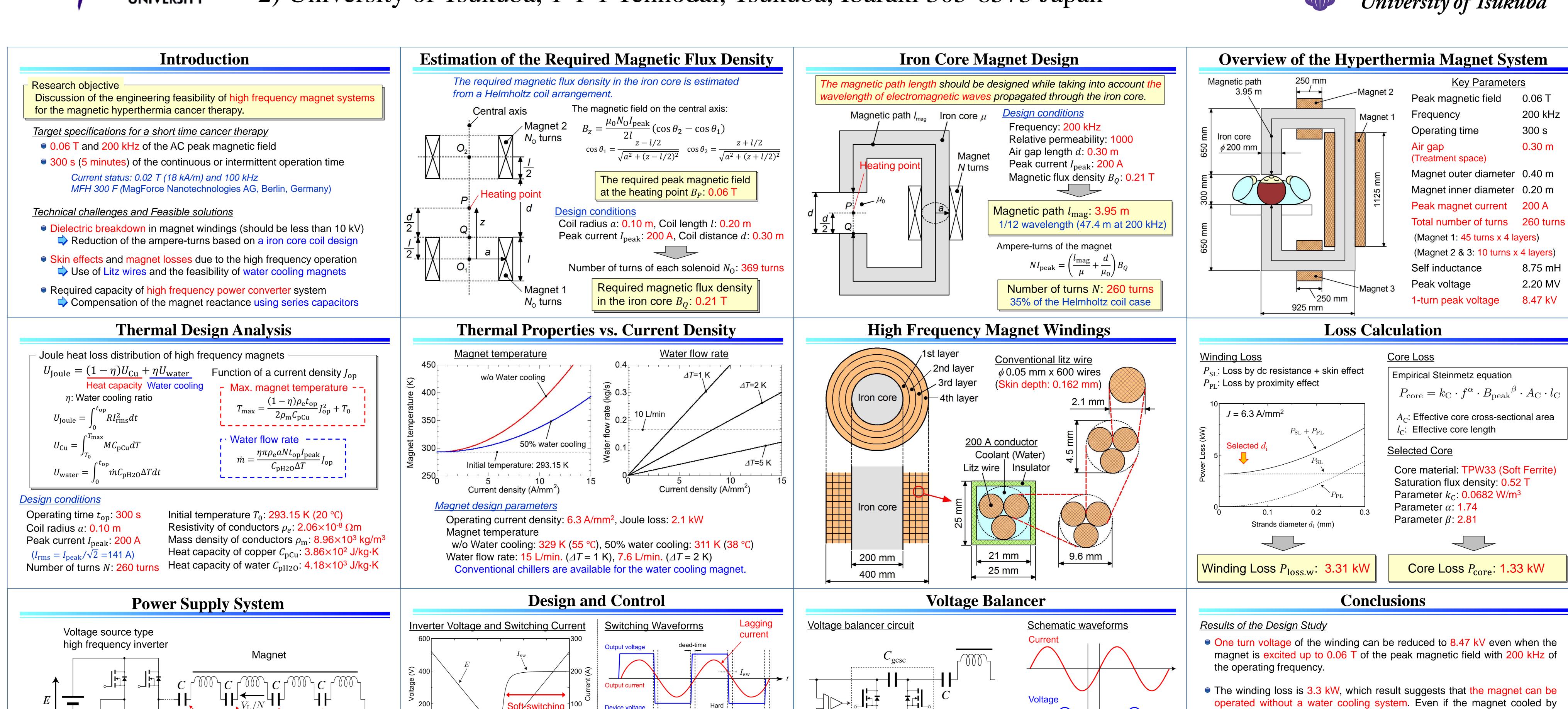
Design Study on High Frequency Magnets for Magnetic Hyperthermia Applications

Shinichi NOMURA¹⁾ and Takanori ISOBE²⁾



- 1) Meiji University, 1-1-1 Higashimita, Tama-ku, Kawasaki, Kanagawa 214-8571 Japan
- 2) University of Tsukuba, 1-1-1 Tennodai, Tsukuba, Ibaraki 305-8573 Japan





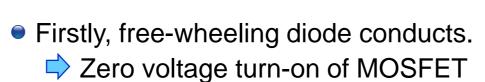
Maximum voltage to ground can be 1-turn peak voltage 8.47 kV.

SiC-MOSFET

(300 A / module)

- SiC-MOSFET can be operated with soft-switching, 200 kHz operation is feasible.
- A separated-by-turn configuration to make voltages to ground low as possible

Series resonant capacitors



Device voltage

Device current

Frequency (kHz)

Equivalent resistance $R_{loss.all}$: 0.232 Ω

Highly frequency sensitive system

➡ Inverter voltage control is applied.

Inductance L: 8.75 mH

- No parasitic capacitor shorting
- MOSFET turns off. dv/dt is mitigated by parasitic cap. No free-wheeling diode recovery
- Total compensation voltage for 1-turn coil can be partially controlled.
 - Controlling voltage to ground not to be high

GCSC: gate controlled series capacitor

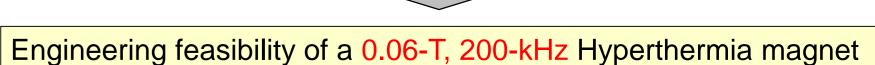
GCSC works as variable capacitor.

Equivalent reactance

 $X_{\rm GCSC} = X_{\rm c} \left(\frac{2\delta}{\pi} - \frac{\sin 2\delta}{\pi} \right)$

 $X_{\rm C}$: Reactance of equipped capacitor

- operated without a water cooling system. Even if the magnet cooled by water, conventional chillers are available.
- Single voltage source high frequency inverter using commercially available SiC-MOSFET (< 1.2 kV) can drive the magnet with balancer circuits.



Future works

- Developing laboratory proto-type for particles and medical investigations
- > Experimental verifications of the proposed design principles of the system